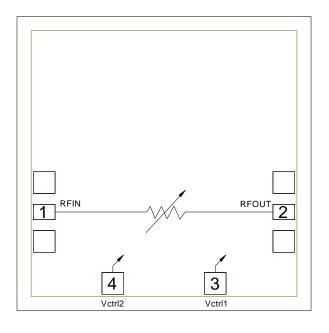


18-40 GHz Voltage - Variable Attenuator

Product Overview

The CMD172 is wideband GaAs MMIC absorptive Voltage-Variable Attenuator (VVA) die which operates from 18 to 40 GHz. The VVA uses a single DC control voltage of -3V to 0V to control RF signal levels over a 37 dB dynamic range. The CMD172 has an extremely low insertion loss of 1.6 dB and is a 50 ohm matched design which eliminates the need for RF port matching. The CMD172 offers full passivation for increased reliability and moisture protection.

Functional Block Diagram



Key Features

- Ultra Wideband Performance
- Low Insertion Loss
- Wide Attenuation Range
- Small Die Size

Ordering Information

Part No.	Description
CMD172	50 pcs gel pack

Electrical Performance ($V_{ctl} = -3.0 \text{ V}$ to 0 V, $T_A = 25^{\circ} \text{ C}$, F = 30 GHz)

Parameter	Min	Тур	Max	Units
Frequency Range		18 - 40		GHz
Insertion Loss		1.6		dB
Attenuation Range		37		dB
Input Return Loss		12		dB
Output Return Loss		12		dB
Input IP3		25		dBm



18-40 GHz Voltage - Variable Attenuator

Absolute Maximum Ratings

Parameter	Rating		
Control Voltage, Vctl	-8 V		
RF Input Power (at maximum attenuation)	+25 dBm		
Operating Temperature	-55 to 85° C		
Storage Temperature	-55 to 150° C		
Thermal Resistance, Q _{JC} (maximum attenuation)	202° C/W		

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Recommended Operating Conditions

Parameter	Min	Тур	Max	Units
V _{ctl}	-5.0	-3.0	0	V

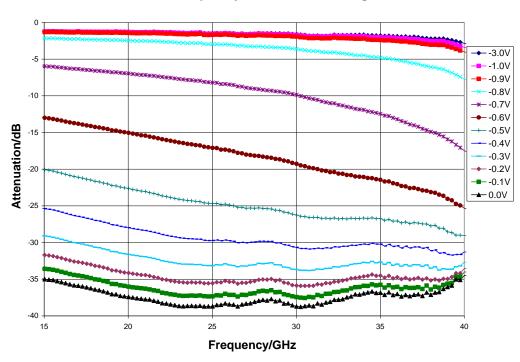
Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications ($V_{ctl} = -3.0 \text{ V to } 0 \text{ V}, T_A = 25^{\circ} \text{ C}$)

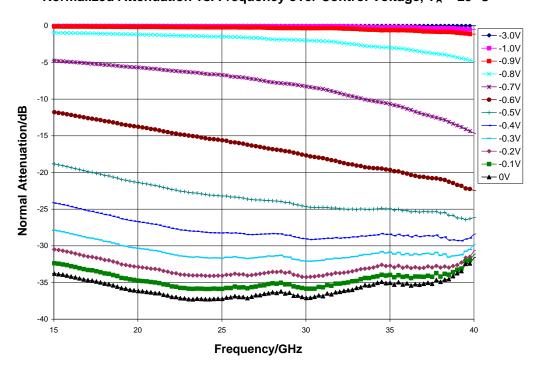
Parameter	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
Frequency Range		18 - 30			30 - 35			35 - 40		GHz
Insertion Loss		1.5	2		1.8	2.5		2.2	3.3	dB
Attenuation Range	33	38		32	37		30	37		dB
Input Return Loss		12			12			10		dB
Output Return Loss		12			12			10		dB
Input IP3		27			24			22		dBm



Attenuation vs. Frequency over Control Voltage, T_A = 25° C

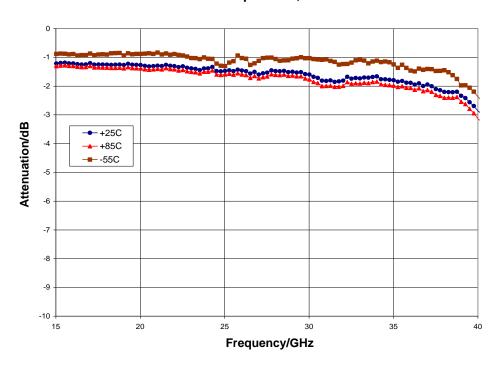


Normalized Attenuation vs. Frequency over Control Voltage, T_A = 25° C

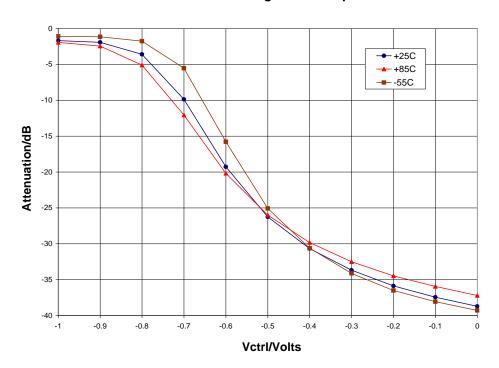




Attenuation over Temperature, Insertion Loss State

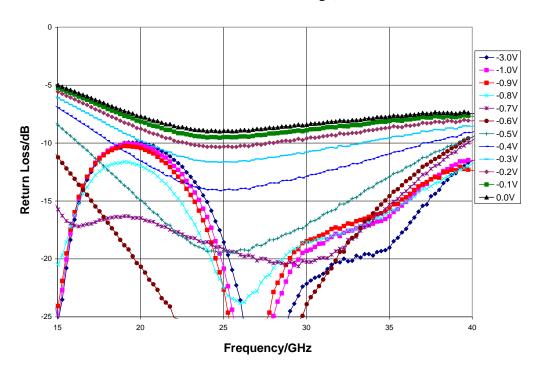


Attenuation vs. Control Voltage over Temperature @ 30 GHz

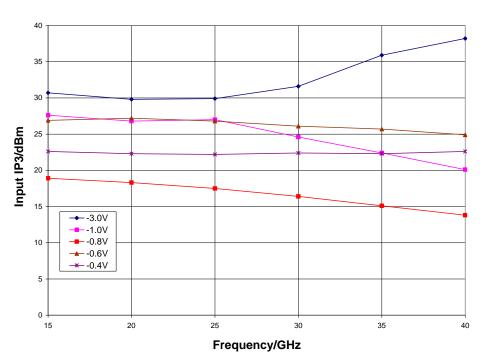




Return Loss vs. Control Voltage, T_A = 25° C

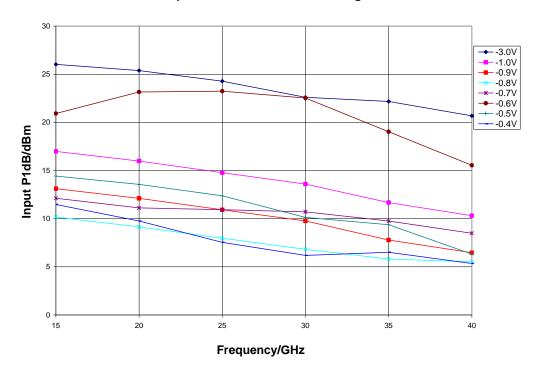


Input IP3 over Control Voltage





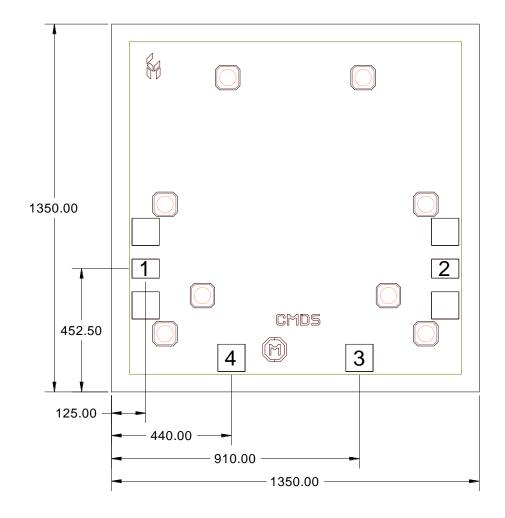
Input P1dB over Control Voltage





Mechanical Information

Die Outline (all dimensions in microns)



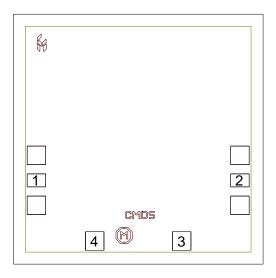
Notes:

- 1. No connection required for unlabeled pads
- 2. Backside is RF and DC ground
- 3. Backside and bond pad metal: Gold
- 4. Die is 85 microns thick
- 5. DC bond pads (3, 4) are 100 x 100 microns
- 6. RF bond pads (1, 2) are 70 x 100 microns



Pad Description

Pad Diagram



Functional Description

Pad	Function	Description	Schematic
1	RF in	DC blocked and 50 ohm matched	RF in
2	RF out	DC blocked and 50 ohm matched	
3	V _{ctrl1}	Control voltage 1	Vctrl1 O—VV
4	V _{ctrl2}	Control voltage 2	Votrl2 O—VV
Backside	Ground	Connect to RF / DC ground	GND ==



Applications Information

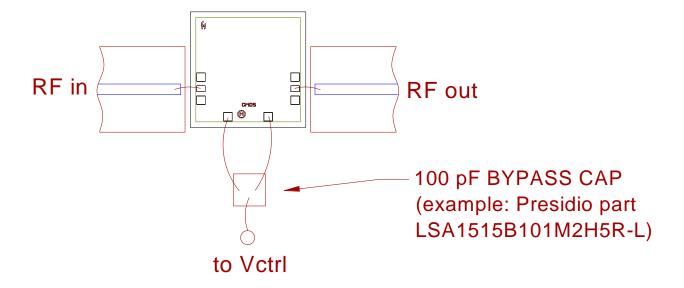
Assembly Guidelines

The backside of the CMD172 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a single bond wire as shown.

The semiconductor is 85 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram



GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



Applications Information

Biasing and Operation

The CMD172 has two control voltages (V_{ctrl1} and V_{ctrl2}) that should be connected together. Full attenuation range is achieved when V_{ctrl} is varied from -3 V to 0 V.

RF power can be applied at any time.

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄0₂) Free
- SVHC Free
- PFOS Free
- Halogen Free



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